

Features

- · Split Gate Trench MOSFET Technology
- Excellent Package for Heat Dissipation
- High Density Cell Design for Low R_{DS(ON)}
- · Moisture Sensitivity Level 1
- Halogen Free. "Green" Device (Note 1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Maximum Ratings

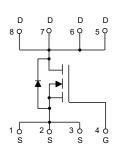
- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 40.7°C/W Junction to Ambient^(Note 2)
- Thermal Resistance: 0.82°C/W Junction to Case

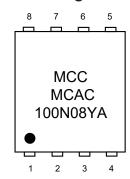
Parameter	Symbol	Rating	Unit		
Drain-Source Voltage		V _{DS}	80	V	
Gate-Source Volltage		V _{GS}	±20	V	
Continuous Drain Current	T _C =25°C		100	Α	
	T _C =100°C	- I _D	63		
Pulsed Drain Current ^(Note3)		I _{DM}	400	Α	
Total Power Dissipation ^(Note4)		P _D	152	W	
Single Pulsed Avalanche Energy ^(Note5)		E _{AS}	600	mJ	

Note:

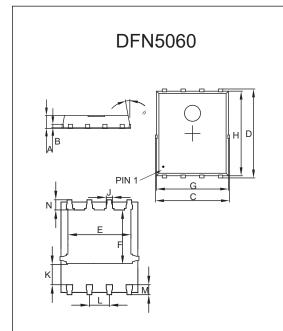
- 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 2. The value of $R_{\theta JA}$ is measured with the device mounted on 1in^2 FR-4 board with 2oz. Copper, in a still air environment with T_A =25°C. The Power dissipation P_{DSM} is based on $R_{\theta JA}$ t≤ 10s and the maximum allowed junction temperature of 150°C. The value in any given application depends on the user's specific board design.
- ${\it 3. Repetitive\ rating; pulse\ width\ limited\ by\ max.\ junction\ temperature.}$
- 4. P_D is based on max. junction temperature, using junction-case thermal resistance.
- 5. T_J =25°C, V_{DD} =50V, V_{GS} =10V, L=3mH, I_{AS} =20A.

Internal Structure and Marking Code





N-CHANNEL MOSFET



DIMENSIONS					
DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	NOTE
Α	0.031	0.047	0.80	1.20	
В	0.010		0.254		TYP.
С	0.193	0.222	4.90	5.64	
D	0.232	0.250	5.90	6.35	
Е	0.148	0.167	3.75	4.25	
F	0.126	0.154	3.20	3.92	
G	0.189	0.213	4.80	5.40	
Н	0.222	0.239	5.65	6.06	
K	0.045	0.059	1.15	1.50	
J	0.012	0.020	0.30	0.50	
L	0.046	0.054	1.17	1.37	
М	0.012	0.028	0.30	0.71	
N	0.016	0.028	0.40	0.71	



Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static Characteristics			-	1			
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =250μA	80			V	
Gate-Source Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±20V			±100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =80V, V _{GS} =0V			1	μA	
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_D=250\mu A$	1.0	1.8	2.5	V	
Drain-Source On-Resistance	_	V _{GS} =10V, I _D =20A		3.6			
	R _{DS(on)}	V _{GS} =4.5V, I _D =20A	4.8 6		6.5	- mΩ	
Gate Resistance	R _g	f=1 MHz, Open drain		2		Ω	
Diode Characteristics			·				
Continuous Body Diode Current	Is				100	Α	
Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _S =20A		0.8	1.2	V	
Reverse Recovery Time	t _{rr}	L 500 H / H 4000/		54		ns	
Reverse Recovery Charge	Q _{rr}	l _F =50A, dl _F /dt=100A/μs		63		nC	
Dynamic Characteristics			·				
Input Capacitance	C _{iss}			6268			
Output Capacitance	C _{oss}	V _{DS} =40V,V _{GS} =0V,f=1MHz		864		pF	
Reverse Transfer Capacitance	C _{rss}			84			
Total Gate Charge	Q _g			92			
Gate-Source Charge	Q_{gs}	V _{DS} =40V,V _{GS} =10V,I _D =50A		20		nC	
Gate-Drain Charge	Q_{gd}			15			
Turn-On Delay Time	t _{d(on)}			20			
Turn-On Rise Time	t _r	V _{DD} =40V, V _{GS} =10V,		33		ns	
Turn-Off Delay Time	t _{d(off)}	$R_{GEN}=3\Omega$, $I_{DS}=50A$		77			
Turn-Off Fall Time	t _f			22			



Curve Characteristics

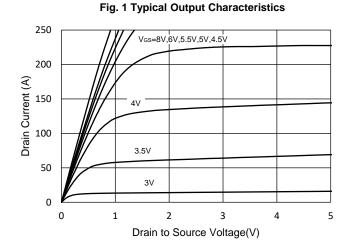


Fig.2 Transfer Characteristic

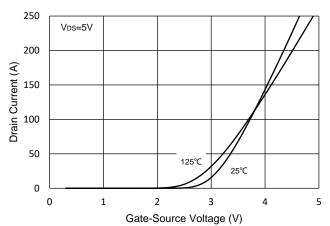


Fig.3 Rdson-Vgs

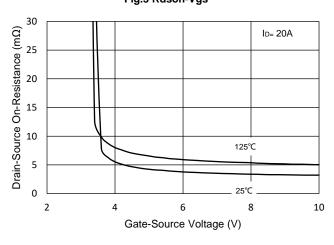


Fig.4 RDS(ON)-ID

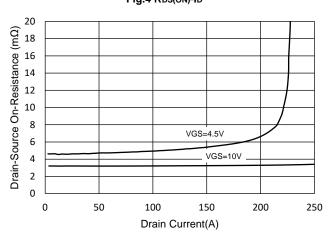


Fig.5 Capacitance Characteristics

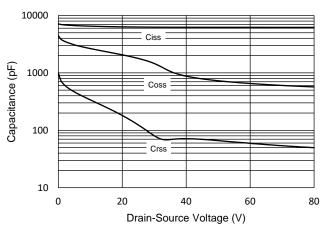
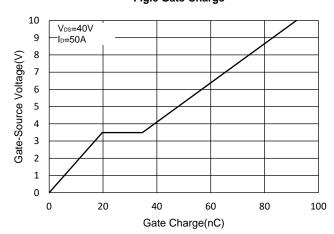
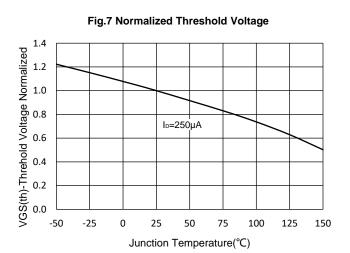


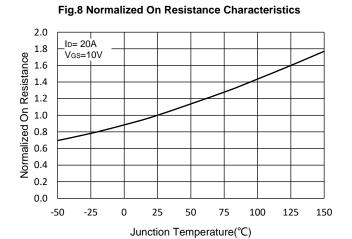
Fig.6 Gate Charge

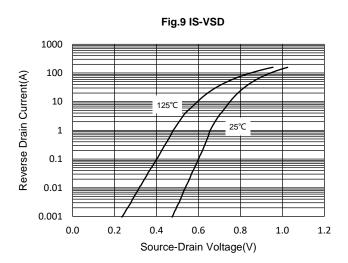


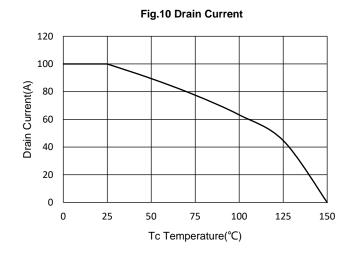


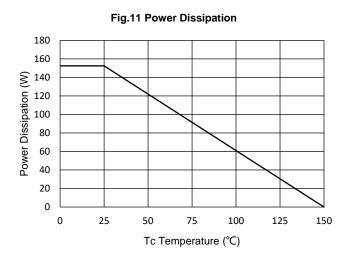
Curve Characteristics













Curve Characteristics

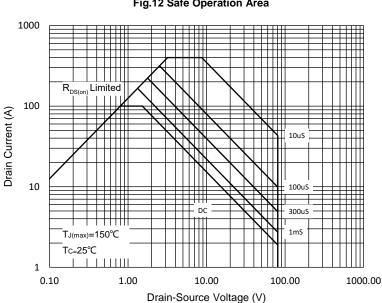
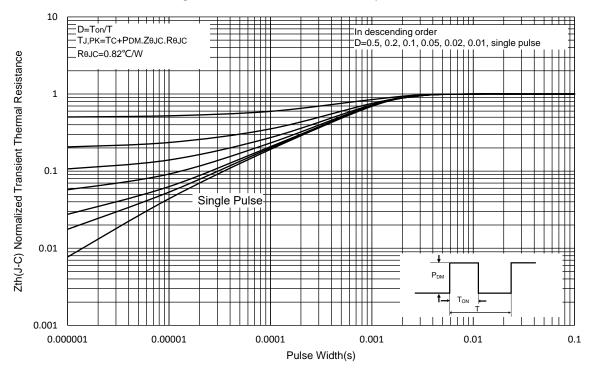


Fig.12 Safe Operation Area







Ordering Information

Device	Packing	
Part Number-TP	Tape&Reel: 5Kpcs/Reel	

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